

*WPA  
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DOCKET NO. MICHEJDA 4-6

PATENT

*#P/A  
Brook  
J. Michael  
2/4/03*

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

John A. Michejda, et al.

Serial No.: 09/882,911

Filed: June 15, 2001

For: A SEMICONDUCTOR DEVICE HAVING A GHOST SOURCE DRAIN REGION AND A METHOD OF MANUFACTURE THEREFOR

Group No.: 2815

Examiner: Fenty, Jesse A.

Honorable Commissioner of Patents  
Washington, D.C. 20231

I hereby certify that one copy of this paper is being deposited with the United States Postal Service as first class mail in an envelope addressed to: "Commissioner of Patents and Trademarks, Washington, D.C. 20231" on 6/24/02.  
Glenn D. Schimmele  
 (Printed name and title or name of service mark or trade name)  
Glenn D. Schimmele  
 (Signature of the person depositing the paper)

Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed March 14, 2002, please amend the above-identified application as follows:

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IN THE CLAIMS:

JAN 30 2003

(1) Kindly rewrite Claim 1 as follows:

TECHNOLOGY CENTER 2800

- A 1
1. (Amended) A semiconductor device, comprising:  
 a channel region located in a semiconductor substrate;  
 a trench located adjacent a side of the channel region;